

# 7-Stage Ripple Carry Binary Counter

#### **Features**

Wide supply voltage range: 3.0V to 15V

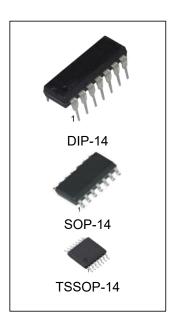
• High noise immunity: 0.45 V<sub>DD</sub> (typ.)

 Low power TTL compatibility: Fan out of 2 driving 74L or 1 driving 74LS

High speed: 12 MHz (typ.)

input pulse rate  $V_{DD} - V_{SS} = 10V$ 

Fully static operation



# **Ordering Information**

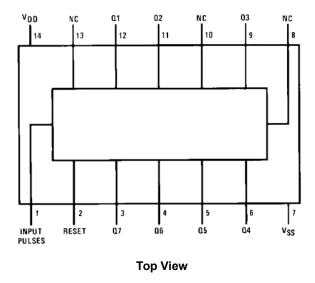
DEVICE	Package Type	MARKING	Packing	Packing Qty
CD4024BE/ CD4024BN	DIP-14	CD4024B	TUBE	1000pcs/box
CD4024BM/TR	SOP-14	CD4024B	REEL	2500pcs/reel
CD4024BMT/TR	TSSOP-14	CD4024B	REEL	2500pcs/reel



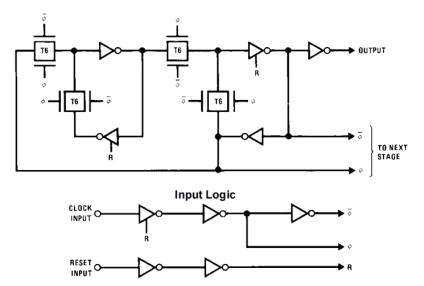
## **General Description**

The CD4024B is a 7-stage ripple-carry binary counter. Buffered outputs are externally available from stages 1 through 7. The counter is reset to its logical "0" stage by a logical "1" on the reset input. The counter is advanced one count on the negative transition of each clock pulse.

# **Connection Diagram**



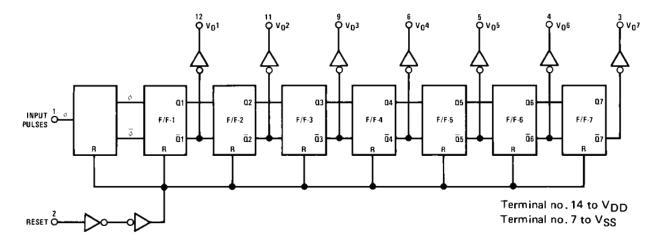
# **Logic Diagrams**



Flip-flop logic (1 of 7 identical stages).



## **Block Diagram**



## **Absolute Maximum Ratings**

Co	ondition	Min	Max	UNITS
DC Supply Voltage (V <sub>DD</sub> )		-0.5	18	V
Input Voltage (V <sub>IN</sub> )		-0.5	0.5	V
Storage Temperature Ran	ge (T <sub>S</sub> )	-65	150	°C
Power Dissipation (P <sub>D</sub> )	Dual-In-Line	-	700	mW
	Small Outline	-	500	mW
Lead Temperature (Solder	ing, 10 seconds)	-	260	°C

**Note 1**: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed, they are not meant to imply that the devices should be operated at these limits. The table of "Recommended Operating Conditions" and "Electrical Characteristics" provides conditions for actual device operation.

**Note 2**:  $V_{SS} = 0V$  unless otherwise specified.

## **Recommended Operating Conditions**

Condition	Min	Max	UNITS
DC Supply Voltage (V <sub>DD</sub> )	3	15	٧
Input Voltage (V <sub>IN</sub> )	0	$V_{DD}$	٧
Operating Temperature Range (T <sub>A</sub> )	-40	85	Ĵ



# **DC Electrical Characteristics**

0	D	O a maliki a ma	-4	0°C	25°C			85°C		Unito	
Symbol	Parameter	Conditions	Min	Max	Min	Тур	Max	Min	Max	Units	
	Ouissant	$V_{DD} = 5V$		5		0.3	5		150		
I <sub>DD</sub>	Quiescent	V <sub>DD</sub> = 10V		10		0.5	10		300	μΑ	
	Device Current	V <sub>DD</sub> = 15V		20		0.7	20		600		
		l <sub>0</sub>  <1 μΑ									
\ \ \/	LOW Level	$V_{DD} = 5V$		0.05		0	0.05		0.05	.,	
V <sub>OL</sub>	Output Voltage	$V_{DD} = 10V$		0.05		0	0.05		0.05	V	
		V <sub>DD</sub> = 15V		0.05		0	0.05		0.05		
		l <sub>0</sub>  <1 μA									
V <sub>OH</sub>	HIGH Level	$V_{DD} = 5V$	4.95		4.95	5		4.95		\ \	
VOH	Output Voltage	V <sub>DD</sub> = 10V	9.95		9.95	10		9.95		V	
		V <sub>DD</sub> = 15V	14.95		14.95	15		14.95			
		l <sub>0</sub>  <1 μA									
V <sub>IL</sub>	LOW Level	$V_{DD}$ = 5V, $V_{O}$ = 0.5V or 4.5V		1.5			1.5		1.5	v	
V IL	Input Voltage	$V_{DD} = 10V$ , $V_{O} = 1.0V$ or 9.0V		3.0			3.0		3.0	v	
		$V_{DD}$ = 15V, $V_{O}$ = 1.5V or 13.5V		4.0			4.0		4.0		
		l <sub>0</sub>  <1 μA									
V <sub>IH</sub>	HIGH Level	$V_{DD} = 5V$ , $V_{O} = 0.5V$ or 4.5V	3.5		3.5			3.5		v	
VIH	Input Voltage	$V_{DD} = 10V$ , $V_{O} = 1.0V$ or $9.0V$	7.0		7.0			7.0		v	
		$V_{DD}$ = 15V, $V_{O}$ = 1.5V or 13.5V	11.0		11.0			11.0			
	LOW Level Output	$V_{DD} = 5V, V_{O} = 0.4V$	0.64		0.51	0.88		0.36			
I <sub>OL</sub>	Current (Note 3)	$V_{DD} = 10V, V_{O} = 0.5V$	1.6		1.3	2.25		0.9		mA	
	Guirent	$V_{DD} = 15V, V_{O} = 1.5V$	4.2		3.4	8.8		2.4			
	HIGH Level Output	$V_{DD} = 5V, V_{O} = 4.6V$	-0.64		-0.51	-0.88		-0.36			
Іон	Current (Note 3)	$V_{DD} = 10V, V_{O} = 9.5V$	-1.6		-1.3	-2.25		-0.9		mA	
	Garront	$V_{DD} = 15V, V_{O} = 13.5V$	-4.2		-3.4	-8.8		-2.4			
I <sub>IN</sub>	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.1		-10 <sup>-5</sup>	-0.1		-1.0	μΑ	
IIN	Input Ourient	$V_{DD} = 15V, V_{IN} = 15V$		0.1		10 <sup>-5</sup>	0.1		1.0	μΛ	

Note 3:  $I_{\text{OH}}$  and  $I_{\text{OL}}$  are tested one output at a time.



## **AC Electrical Characteristics** (Note 4)

 $T_{\text{A}}$  = 25°C,  $C_{\text{L}}$  = 50 pF,  $R_{\text{L}}$  = 200 k,  $t_{\text{r}}$  and  $t_{\text{f}}$  = 20 ns unless otherwise specified

Symbol	Parameter	Conditions	Min	Тур	Max	Units
	Drangation Dalay	V <sub>DD</sub> = 5V		185	350	
$t_{PHL}$ , $t_{PLH}$	Propagation Delay	V <sub>DD</sub> = 10V		85	125	ns
	Time to Q1 Output	V <sub>DD</sub> = 15V		70	100	
		$V_{DD} = 5V$		100	200	
$t_{THL}$ , $t_{TLH}$	Transition Time	V <sub>DD</sub> = 10V		50	100	ns
		V <sub>DD</sub> = 15V		40	80	
	Minimum Input	$V_{DD} = 5V$		75	200	
$t_{WL},\;t_{WH}$	· ·	V <sub>DD</sub> = 10V		40	110	ns
	Pulse Width	V <sub>DD</sub> = 15V		35	90	
		$V_{DD} = 5V$			15	
t <sub>RCL</sub> , t <sub>FCL</sub>	Input Rise and Fall Time	V <sub>DD</sub> = 10V			10	μs
		V <sub>DD</sub> = 15V			8	
	Massiness les most	$V_{DD} = 5V$	1.5	5		
$f_{CL}$	Maximum Input	V <sub>DD</sub> = 10V	4	12		MHz
	Pulse Frequency	V <sub>DD</sub> = 15V	5	15		
	Danat Duamanation Dalam	$V_{DD} = 5V$		185	350	
t <sub>PHL</sub>	Reset Propagation Delay	V <sub>DD</sub> = 10V		85	125	ns
	Time	V <sub>DD</sub> = 15V		70	100	
	D t. N	V <sub>DD</sub> = 5V		185	350	
$t_WH$	Reset Minimum	V <sub>DD</sub> = 10V		85	125	ns
	Pulse Width	V <sub>DD</sub> = 15V		70	100	
Cin	Input Capacitance (Note 5)	Any Input		5	7.5	pF

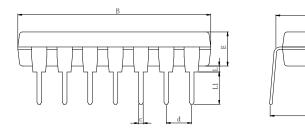
Note 4: AC Parameters are guaranteed by DC correlated testing.

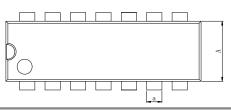
Note 5: Capacitance is guaranteed by periodic testing



# **Physical Dimensions**

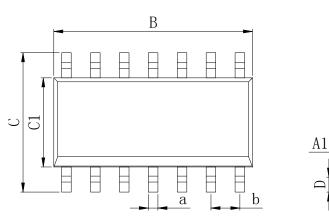
## DIP-14





Dimensions In Millimeters(DIP-14)										
Symbol:	Α	В	D	D1	Е	L	L1	а	С	d
Min:	6.10	18.94	8.10	7.42	3.10	0.50	3.00	1.50	0.40	2.54.BSC
Max:	6.68	19.56	10.9	7.82	3.55	0.70	3.60	1.55	0.50	2.54 BSC

SOP-14



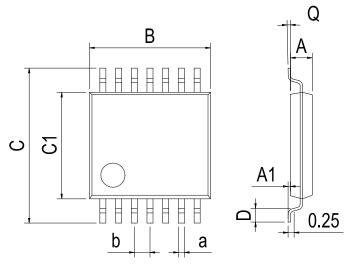
Dimensions In Millimeters(SOP-14)										
Symbol:	Α	A1	В	С	C1	D	Q	а	b	
Min:	1.35	0.05	8.55	5.80	3.80	0.40	0°	0.35	4 27 BCC	
Max:	1.55	0.20	8.75	6.20	4.00	0.80	8°	0.45	1.27 BSC	

0.25



# **Physical Dimensions**

## TSSOP-14



Dimensions In Millimeters(TSSOP-14)									
Symbol:	Α	A1	В	С	C1	D	Q	а	b
Min:	0.85	0.05	4.90	6.20	4.30	0.40	0°	0.20	0.65.000
Max:	0.95	0.20	5.10	6.60	4.50	0.80	8°	0.25	0.65 BSC



# **Revision History**

DATE	REVISION	PAGE
2019-1-13	New	1-9
2024-10-25	Update Lead Temperature	3



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